

View Online at <https://aerobasegroup.com/nsn/5961-01-344-0958>

**Inclosure Material:**

Metal

**Mounting Facility Quantity:**

2

**Component Name And Quantity:**

4 transistor

**Mounting Method:**

Unthreaded hole

**Features Provided:**

Hermetically sealed case

**Semiconductor Material:**

Silicon all transistor

**Voltage Rating In Volts Per Characteristic:**

500.0 drain to source voltage all transistor

**Current Rating Per Characteristic:**

164.00 amperes off-state current, peak all transistor and 41.00 amperes drain current all transistor

**Power Rating Per Characteristic:**

400.0 watts total device dissipation all transistor

**Maximum Operating Temperature Per Measurement Point:**

150.0 degrees celsius junction

**Terminal Type And Quantity:**

8 uninsulated wire lead

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fig:**

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